

Solid State Relay OCMOS FET

PS7142-1A,PS7142L-1A

6-PIN DIP, 400 V BREAK DOWN VOLTAGE 1-ch Optical Coupled MOS FET

DESCRIPTION

The PS7142-1A and PS7142L-1A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

They are suitable for analog signal control because of their low offset and high linearity.

The PS7142L-1A has a surface mount type lead.

FEATURES

- 1 channel type (1 a output)
- Low LED operating current (IF = 2 mA)
- · Designed for AC/DC switching line changer
- Small package (6-pin DIP)
- · Low offset voltage
- PS7142L-1A: Surface mount type
- UL approved: File No. E72422 (S)
- BSI approved: No. 8245/8246
- CSA approved: No. CA 101391

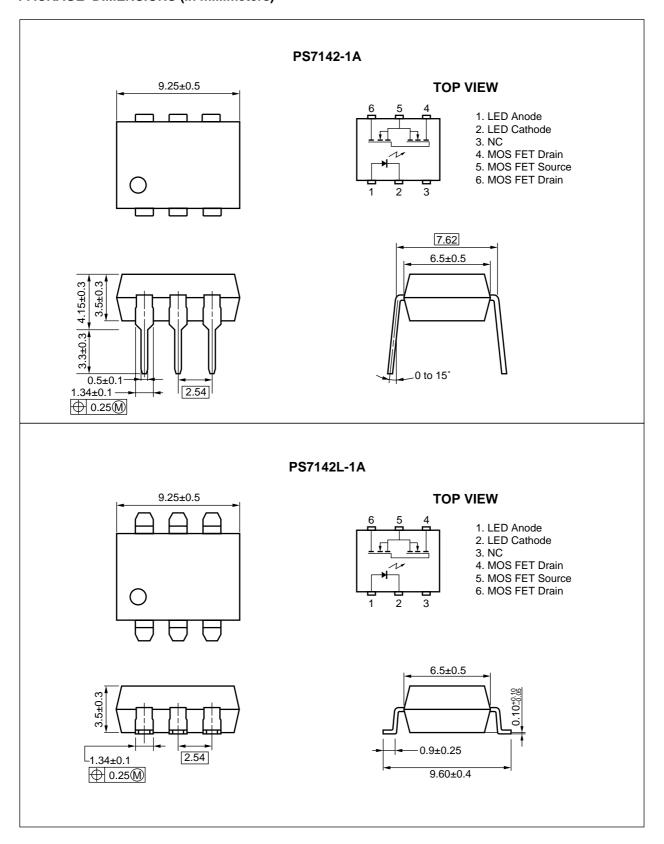
APPLICATIONS

- · Exchange equipment
- Measurement equipment
- FA/OA equipment

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Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

PACKAGE DIMENSIONS (in millimeters)



ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number*1
PS7142-1A	6-pin DIP	Magazine case 50 pcs	PS7142-1A
PS7142L-1A			PS7142L-1A
PS7142L-1A-E3		Embossed Tape 1 000 pcs/reel	
PS7142L-1A-E4			

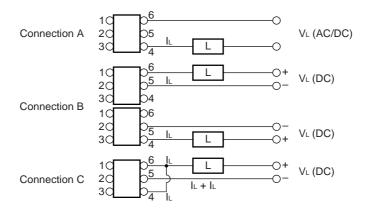
^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter			Symbol	Ratings	Unit
Diode	Forward Current (DC)		lF	50	mA
	Reverse Voltage		VR	5.0	V
	Power Dissipation		Po	50	mW
	Peak Forward Current *1		IFP	1	Α
MOS FET	T Break Down Voltage		VL	400	V
	Continuous	Connection A	lι	200	mA
	Load Current *2	Connection B		250	
		Connection C		400	
	Pulse Load Current ** (AC/DC Connection) Power Dissipation		ILP	400	mA
			Po	560	mW
Isolation Voltage ^{*4}			BV	1 500	Vr.m.s.
Total Power Dissipation			P⊤	610	mW
Operating Ambient Temperature			TA	-40 to +85	°C
Storage Te	Storage Temperature			-40 to +100	°C

^{*1} PW = 100 μ s, Duty Cycle = 1 %

^{*2} Conditions: IF \geq 2 mA. The following types of load connections are available.



^{*3} PW = 100 ms, 1 shot

^{*4} AC voltage for 1 minute at $T_A = 25$ °C, RH = 60 % between input and output

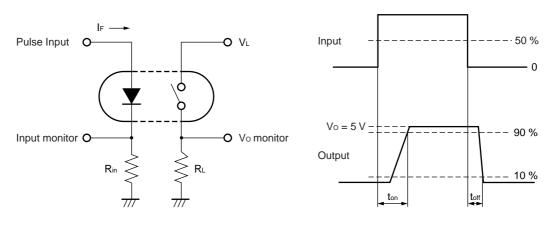
RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

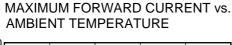
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

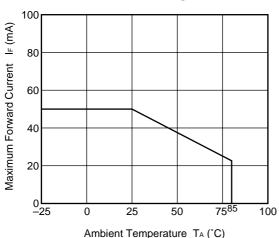
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
	Reverse Current	lR	V _R = 5 V			5.0	μΑ
MOS FET	Off-state Leakage Current	Loff	V _D = 400 V		0.03	1.0	μΑ
	Output Capacitance	Cout	V _D = 0 V, f = 1 MHz		225		pF
Coupled	LED On-state Current	IFon	IL = 200 mA			2.0	mA
	On-state Resistance	Ron1	IF = 10 mA, IL = 10 mA		6.0	10	Ω
		Ron2	$I_F = 10 \text{ mA}, I_L = 200 \text{ mA}, t \le 10 \text{ ms}$				
	Turn-on Time 1	ton	I _F = 10 mA, V _O = 5 V, R _L = 500 Ω,		0.8	5.0	ms
	Turn-off Time ^{*1}	toff	PW ≥ 10 ms		0.02	0.2	
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVpc	10°			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		1.1		pF

*1 Test Circuit for Switching Time

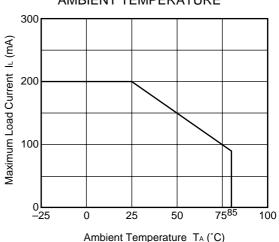


★ TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

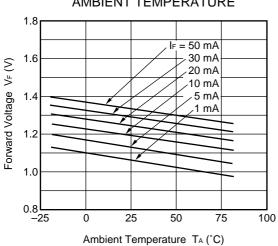




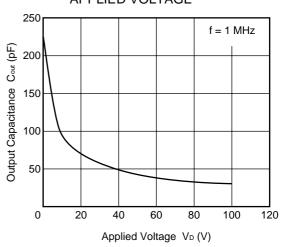
MAXIMUM LORD CURRENT vs. AMBIENT TEMPERATURE



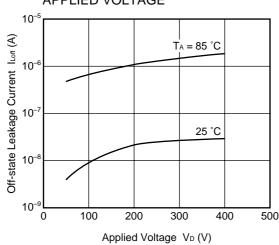
FORWARD VOLTAGE vs. AMBIENT TEMPERATURE



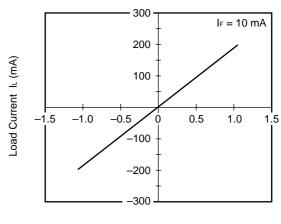
OUTPUT CAPACITANCE vs. APPLIED VOLTAGE



OFF-STATE LEAKAGE CURRENT vs. APPLIED VOLTAGE

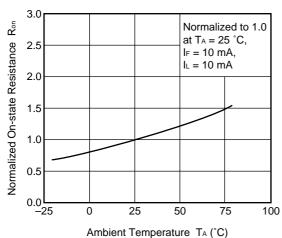


LORD CURRENT vs. LORD VOLTAGE

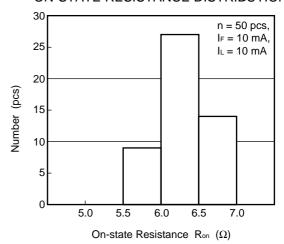


Load Voltage V_L (V)

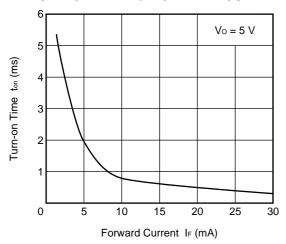
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



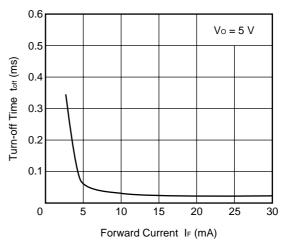
ON-STATE RESISTANCE DISTRIBUTION



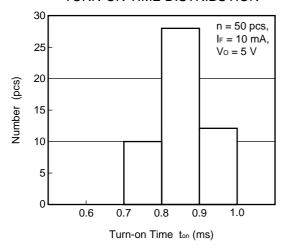
TURN-ON TIME vs. FORWARD CURRENT



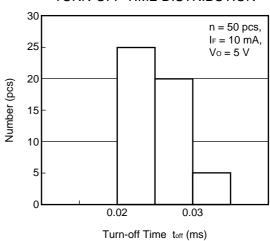
TURN-OFF TIME vs. FORWARD CURRENT



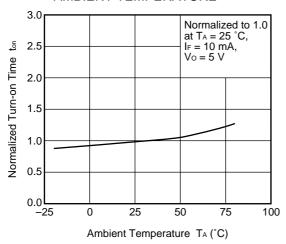
TURN-ON TIME DISTRIBUTION



TURN-OFF TIME DISTRIBUTION

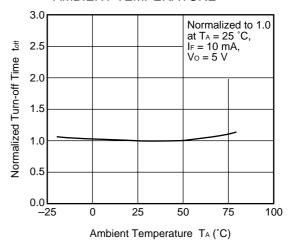


NORMALIZED TURN-ON TIME vs. AMBIENT TEMPERATURE

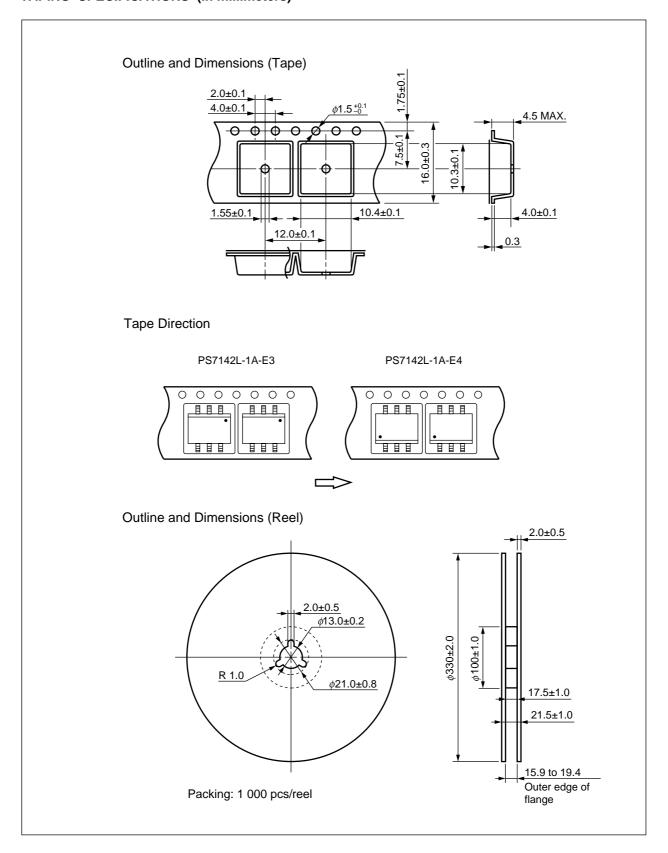


Remark The graphs indicate nominal characteristics.

NORMALIZED TURN-OFF TIME vs. AMBIENT TEMPERATURE



★ TAPING SPECIFICATIONS (in millimeters)



★ RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

Peak reflow temperature
 260°C or below (package surface temperature)

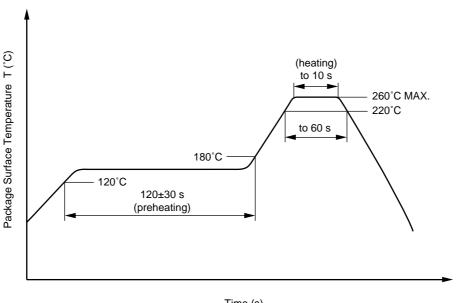
Time of peak reflow temperature
 Time of temperature higher than 220°C
 60 seconds or less

Time to preheat temperature from 120 to 180°C 120±30 s
 Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

• Preheating conditions 120°C or below (package surface temperature)

• Number of times One

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

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M8E 00.4-0110

SAFETY INFORMATION ON THIS PRODUCT

Cai	Ition

GaAs Products

The product contains gallium arsenide, GaAs.

GaAs vapor and powder are hazardous to human health if inhaled or ingested.

- Do not destroy or burn the product.
- Do not cut or cleave off any part of the product.
- Do not crush or chemically dissolve the product.
- Do not put the product in the mouth.

Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.

▶For further information, please contact

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